

**Списък на забелязаните цитати  
на гл. ас. д-р Емил Манолов**

**1. L.I. Popova, S.K. Andreev, V.K. Gueorguiev, E.B. Manolov, Resistance Changes of SnO<sub>2</sub> Thin Films Suitable for Microelectronic Gas Sensors, Proc. 20<sup>th</sup> International Conference on Microelectronics (MIEL'95), Vol. 2, pp.581-583, Niš, Serbia, 12 – 14 September, 1995.**

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**Общ брой цитирания – 77 (69 цитирания в списания и 8 цитирания в дисертации)**